Panasonic

ideas for life

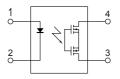
Ultra minimum package size, SSOP (1 Form A) 4-pin type. Lower output capacitance (C type) and on resistance (R type). (C \times R10)

RF PhotoMOS (AQY221O2V)

FEATURES



mm inch



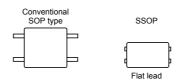
1. Reduced package size

Lower surface has been reduced 60% and mounting space 40% compared to conventional 4-pin SOP type.

2. Two types are available: A type with greatly reduced ON resistance, and a type with even lower output capacitance between terminals.

	AQY221R2V (R Type)	AQY221N2V (C Type)
Output capacitance (C)	12.5pF	1.0pF
ON resistance (R)	0.75Ω	9.5Ω

3. Mounting space has been reduced and output signals have been improved by using new flat lead terminals.



4. High speed switching (Part No.: AQY221N2V)

Turn on time: 0.02ms Turn off time: 0.02ms

TYPICAL APPLICATIONS

Measuring and testing equipment

1. Test equipment

IC tester, Liquid crystal driver tester, semiconductor performance tester

2. Board tester

Bare board tester, In-circuit tester, function tester

3. Medical equipment

Ultrasonic wave diagnostic machine

4. Multi-point recorder

Strainmeter, thermo couple

TYPES

Туре		Output rating*		Part No. (Tape and	Dooking quantity	
		Load voltage	Load current	Picked from the 1/4-pin side	Picked from the 2/3-pin side	Packing quantity
AC/DC	Low on resistance (R Type)	40 V	250 mA	AQY221R2VY	AQY221R2VW	Tape and reel:
type	Low capacitance (C Type)	40 V	120 mA	AQY221N2VY	AQY221N2VW	3,500 pcs.

^{*} Indicate the peak AC and DC values.

Notes: (1) Tape package is the standard packing style.

(2) For space reasons, the initial letters of the product number "AQY", the package type indicator "Y" and "W" are omitted from the seal. (Ex. the label for product number AQY221N2V is 221N2)

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY221R2V	AQY221N2V	Remarks
Input	LED forward current	I F	50mA		
	LED reverse voltage	VR	5V		
	Peak forward current	I FP	1A		f=100 Hz, Duty factor=0.1%
	Power dissipation	Pin	75mW		
Output	Load voltage (peak AC)	VL	40V		
	Continuous load current (peak AC)	Iι	0.25A	0.12A	Peak AC, DC
	Peak load current	Ipeak	0.75A	0.3A	100 ms (1 shot), V∟= DC
	Power dissipation	Pout	250mW		
Total power dissipation		Рт	300mW		
I/O isolation voltage		Viso	1,500V AC		
Temperature limits	Operating	Topr	-40°C to +85°C -40°F to +185°F		Non-condensing at low temperatures
	Storage	T _{stg}	-40°C to +100°C -40°F to +212°F		

RF PhotoMOS (AQY221O2V)

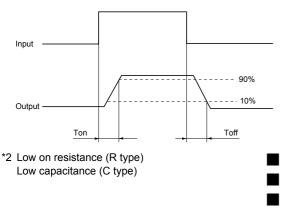
2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY221R2V	AQY221N2V	Condition*2		
Input	LED operate current		Typical	IFon	0.9 mA	1.0 mA	C type (I _L = 80 mA)
			Maximum		3.0	R type (I∟ = 250 mA)	
	LED turn off current		Minimum	l _{Foff}	0.1 mA	0.2 mA	C type (I∟ = 80 mA)
			Typical		0.8 mA	0.9 mA	R type (I∟ = 250 mA)
	LED dropout voltage		Typical	VF	1.35 V (1.14 V	C type (I _F = 50 mA)	
			Maximum	VF	1.5	R type (I _F = 50 mA)	
Output	On resistance		Typical	Ron	0.75Ω	9.5Ω	C type (I _F = 5 mA, I _L = 80 mA Within 1 s on time)
			Maximum		1.25Ω	12.5Ω	R type (I _F = 5 mA, I _L = 250 mA Within 1 s on time)
	Output	Typical		12.5 pF	1.0 pF	I _F = 0 mA	
	capacitance		Maximum	Cout	18 pF	1.5 pF	V _B = 0 V f = 1 MHz
	Off state leakage	Typical	Leak	0.02 nA	0.01 nA	C type (I _F = 0 mA, V _L = Max.)	
	current			Maximum	10	R type ($I_F = 0 \text{ mA}, V_L = \text{Max.}$)	
Transfer characteristics	Switching speed	Turn on time*1	Typical	Ton	0.10 ms	0.02 ms	C type (I _F = 5 mA, V_L = 10 V R_L = 125 Ω)
			Maximum	Ton	0.5	R type (I _F = 5 mA, V _L = 10 V R_L = 40 Ω)	
		Turn off	Typical	Toff	0.08 ms	0.02 ms	C type (I _F = 5 mA, V_L = 10 V R_L = 125 Ω)
		time*1	Maximum	I off	0.2 ms		R type (I _F = 5 mA, V_L = 10 V R_L = 40 Ω)
	I/O capacitance		Typical	Ciso	0.8 pF		C type (f = 1 MHz, V _B = 0 V) R type (f = 1 MHz, V _B = 0 V)
			Maximum	Ciso	1.5		
	Initial I/O isolation resistance Minimum		Riso	1,000ΜΩ		500V DC	

Notes:

2. Variation possible through combinations of output capacitance and ON resistance.

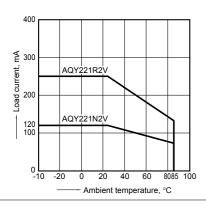
*1 Turn on/Turn off time



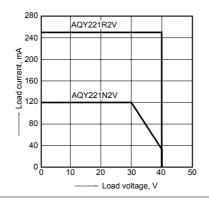
REFERENCE DATA

1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F

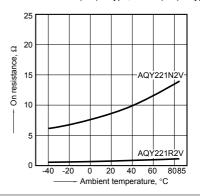


2. Load current vs. Load voltage characteristics Ambient temperature: 25°C 77°F



3. On resistance vs. ambient temperature characteristics

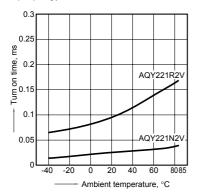
Measured portion: between terminals 3 and 4 LED current: 5 mA; Load voltage: Max. (DC); Load current: 250mA (DC) R type, 80mA (DC) C type



RF PhotoMOS (AQY221O2V)

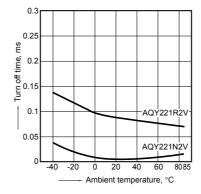
4. Turn on time vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4 LED current: 5 mA; Load voltage: 10V (DC); Continuous load current: 250mA (DC) R type, 80mA (DC) C type



5. Turn off time vs. ambient temperature characteristics

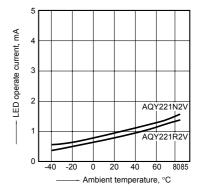
Measured portion: between terminals 3 and 4 LED current: 5 mA; Load voltage: 10V (DC); Continuous load current: 250mA (DC) R type, 80mA (DC) C type



6. LED operate current vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4; Load voltage: Max. (DC);

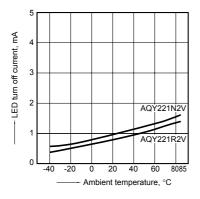
Continuous load current: 250mA (DC) R type, 80mA (DC) C type



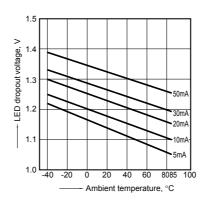
7. LED turn off current vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4; Load voltage: Max. (DC); Continuous load current: 250mA (DC) R type,

80mA (DC) C type

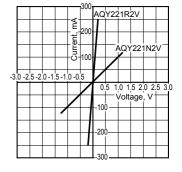


8. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



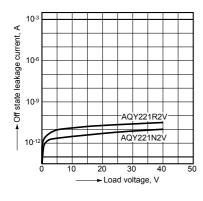
9. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4 Ambient temperature: 25°C 77°F



10. Off state leakage current vs. load voltage characteristics

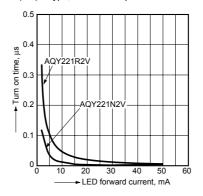
Measured portion: between terminals 3 and 4 Ambient temperature: 25°C 77°F



11. Turn on time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4 Load voltage: 10V (DC);

Continuous load current: 250mA (DC) R type, 80mA (DC) C type; Ambient temperature: 25°C 77°F

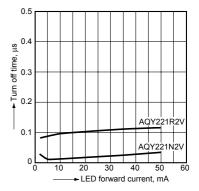


12. Turn off time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4 Load voltage: 10V (DC);

Continuous load current: 250mA (DC) R type,

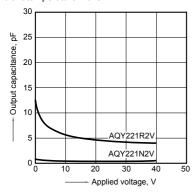
80mA (DC) C type; Ambient temperature: 25°C 77°F



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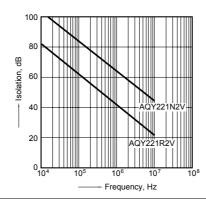
13. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4 Frequency: 1 MHz, 30m Vrms; Ambient temperature: $25^{\circ}C$ $77^{\circ}F$



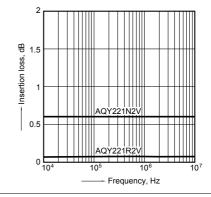
14. Isolation vs. frequency characteristics (50 Ω impedance)

Measured portion: between terminals 3 and 4 Ambient temperature: 25°C 77°F

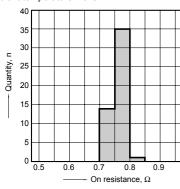


15. Insertion loss vs. frequency characteristics (50 Ω impedance)

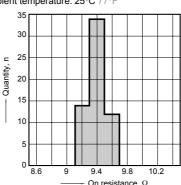
Measured portion: between terminals 3 and 4 Ambient temperature: 25°C 77°F



16-(1). On resistance distribution (R type) Measured portion: between terminals 3 and 4 Continuous load current: 250mA (DC) Ambient temperature: 25°C 77°F

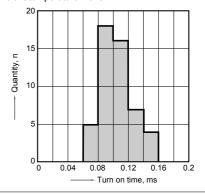


16-(2). On resistance distribution (C type) Measured portion: between terminals 3 and 4 Continuous load current: 80mA (DC) Ambient temperature: 25°C 77°F

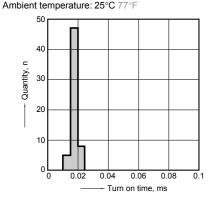


17-(1). Turn on time distribution (R type) Load voltage: 10V (DC)

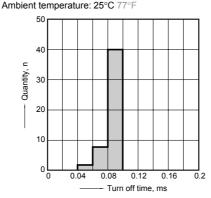
Continuous load current: 250mA (DC) Ambient temperature: 25°C 77°F



17-(2). Turn on time distribution (C type) Load voltage: 10V (DC) Continuous load current: 80mA (DC)

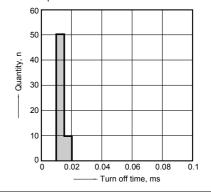


18-(1). Turn off time distribution (R type) Load voltage: 10V (DC) Continuous load current: 250mA (DC)

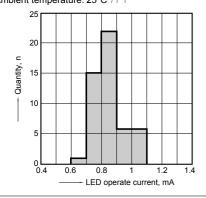


18-(2). Turn off time distribution (C type) Load voltage: 10V (DC)

Continuous load current: 80mA (DC) Ambient temperature: 25°C 77°F



19-(1). LED operate current distribution (R type) Load voltage: 10V (DC) Continuous load current: 250mA (DC) Ambient temperature: 25°C 77°F



19-(2). LED operate current distribution (C type) Load voltage: 10V (DC)

Continuous load current: 80mA (DC) Ambient temperature: 25°C 77°F

